MOC3080, MOC3081, MOC3082, MOC3083

OPTICALLY COUPLED BILATERAL SWITCH LIGHT ACTIVATED ZERO VOLTAGE CROSSING TRIAC

DESCRIPTION

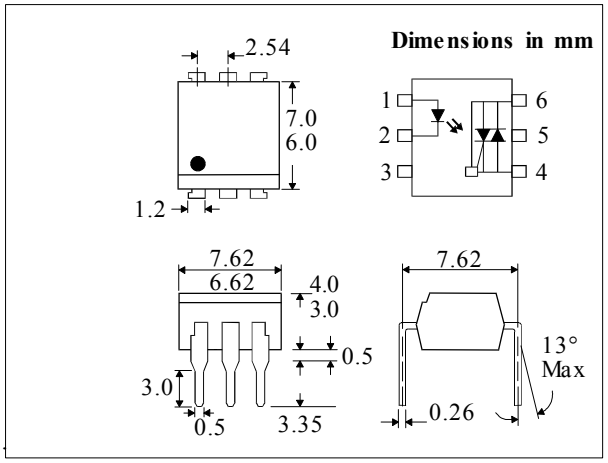
The MOC308_ Series are optically coupled isolators consisting of a Gallium Arsenide infrared emitting diode coupled with a monolithic silicon detector performing the functions of a zero crossing bilateral triac mounted in a standard 6 pin dual-in-line package.

FEATURES

- Options :-
  10mm lead spread - add G after part no.
  Surface mount - add SM after part no.
  Tape&reel - add SMT&R after part no.
- High Isolation Voltage($5.3kV_{RMS}$,$7.5kV_{PK}$)
- Zero Voltage Crossing
- 800V Peak Blocking Voltage
- All electrical parameters 100% tested
- Custom electrical selections available

APPLICATIONS

- CRTs
- Power Triac Driver
- Motors
- Consumer appliances
- Printers



ABSOLUTE MAXIMUM RATINGS
(25 °C unless otherwise noted)

Storage Temperature	-40°C - +150°C
Operating Temperature	-40°C - +100°C
Lead Soldering Temperature	260°C
(1.6mm from case for 10 seconds)	
Input-to-output Isolation Voltage (Pk)	7500 Vac
(60 Hz , 1sec. duration)	

INPUT DIODE

Forward Current	50mA
Reverse Voltage	6V
Power Dissipation	120mW
(derate linearly 1.41mW/°C above 25°C)	

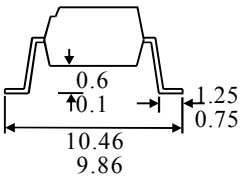
OUTPUT PHOTO TRIAC

Off-State Output Terminal Voltage	800V
RMS Forward Current	100mA
Forward Current (Peak)	1.2A
Power Dissipation	150mW
(derate linearly 1.76mW/°C above 25°C)	

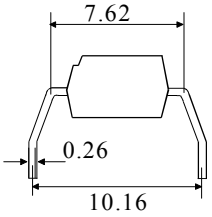
POWER DISSIPATION

Total Power Dissipation	250mW
(derate linearly 2.94mW/°C above 25°C)	

OPTION SM
SURFACE MOUNT



OPTION G



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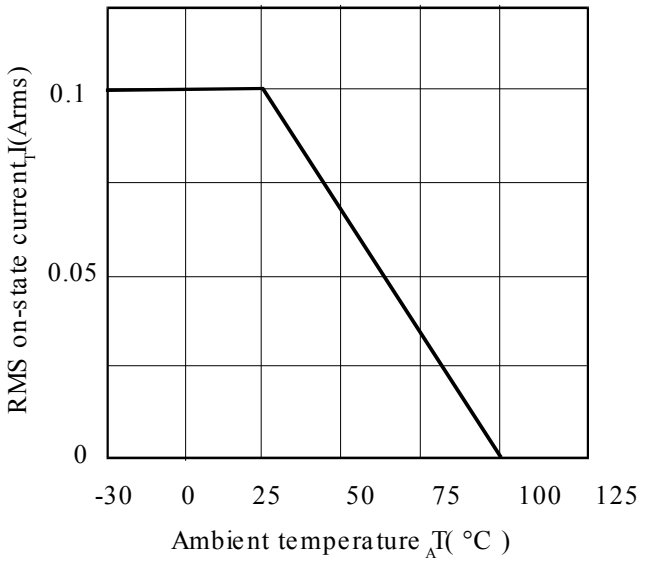
ELECTRICAL CHARACTERISTICS (T_A = 25°C Unless otherwise noted)

PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage (V_F)		1.2	1.5	V	I_F = 30mA
	Reverse Current (I_R)			100	μA	V_R = 6V
Output	Peak Off-state Current (I_{DRM})			300	nA	V_{DRM} = 800V (note 1)
	Peak Blocking Voltage (V_{DRM})	800			V	I_{DRM} = 300nA
	On-state Voltage (V_{TM})		1.8	3.0	V	I_{TM} = 100mA (peak)
	Critical rate of rise of off-state Voltage (dv/dt)	100			V/μs	
Coupled	Input Current to Trigger (I_{FT}) (note 2)					
	MOC3080			30	mA	V_{TM} = 3V (note 2)
	MOC3081			15	mA	
	MOC3082			10	mA	
	MOC3083			5	mA	
	Holding Current , either direction (I_H)		100		μA	
	Input to Output Isolation Voltage (V_{ISO})	5300			V_{RMS}	See note 3
		7500			V_{PK}	See note 3
Zero Crossing Charact--eristic	Inhibit Voltage (V_{IH})			35	V	I_F = Rated I_{FT} MT1-MT2 Voltage above which device will not trigger
	Leakage in Inhibited State (I_S)			500	μA	I_F = Rated I_{FT} V_{DRM} = 800V off-state

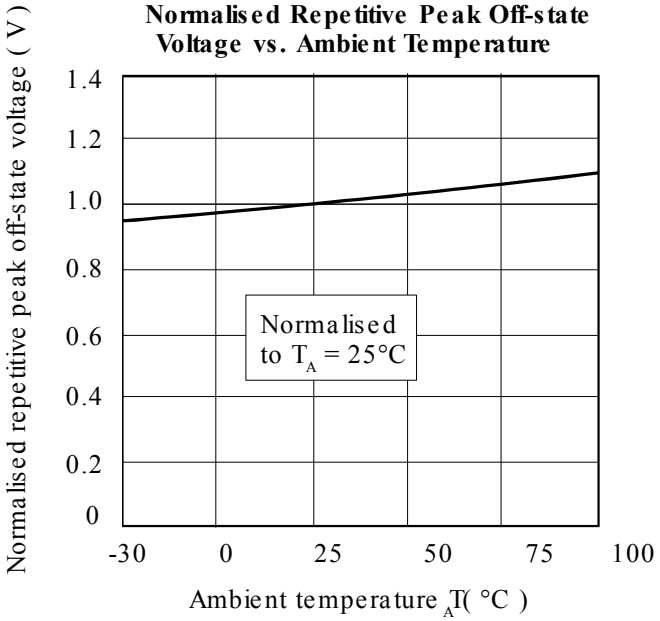
Note 1. Guaranteed to trigger at an I_F value less than or equal to max I_{FT}. Recommended I_F lies between Rated I_{FT} and absolute max I_F.

Note 2. Measured with input leads shorted together and output leads shorted together.

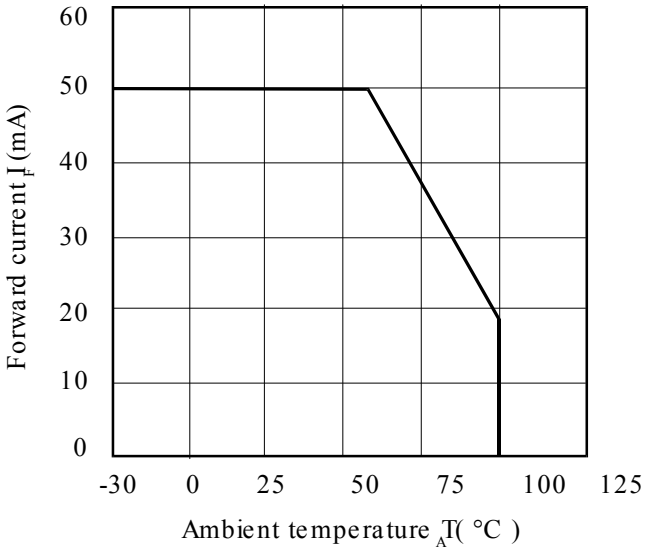
RMS On-state Current vs. Ambient Temperature



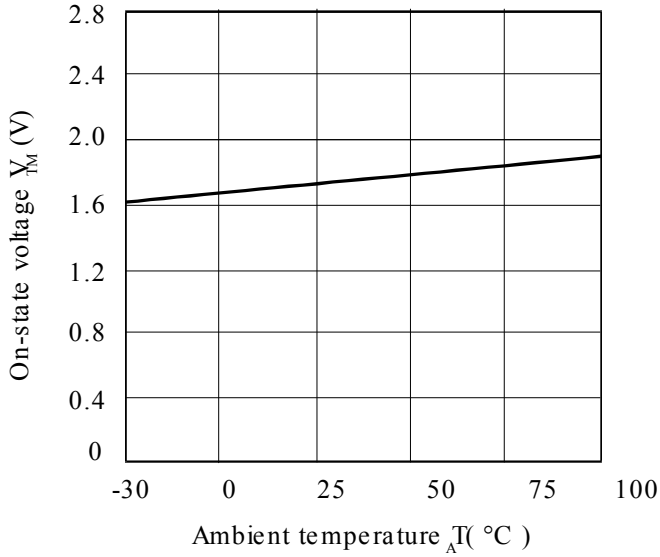
Normalised Repetitive Peak Off-state Voltage vs. Ambient Temperature



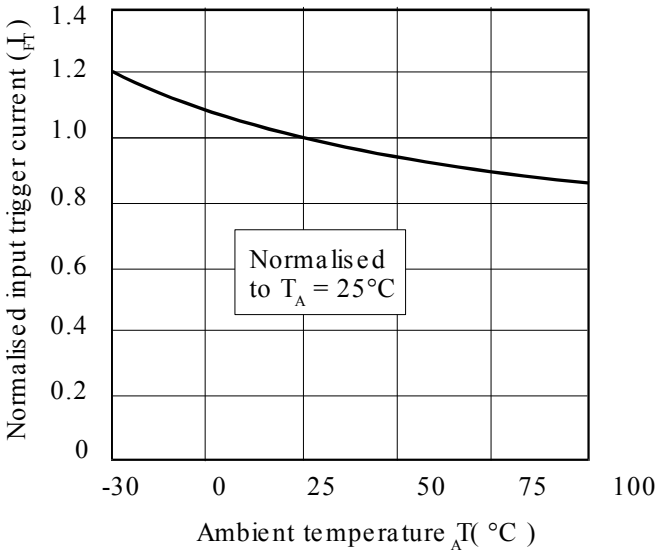
Forward Current vs. Ambient Temperature



On-state Voltage vs. Ambient Temperature



Normalised Input Trigger Current vs. Ambient Temperature



On-state Current vs. On-state Voltage